	Specification	Specification Symbol Condition / Comment						151-30 SiC	151	-60 SiC	Unit
	Maximum Operating Voltage	$V_{O(max)}$	I _{off} < 50 μADC, T _{case} = 70°C						15		kVDC
	Maximum Isolation Voltage	VI			trol / GND, contin	uously	1		± 25		kVDC
CS	Max. Housing Insulation Voltage	V _{INS}	Between switch	Between switch and housing surface, 3 minutes				± 50 k\			
RATING	Maximum Turn-On Peak Current	$I_{P(max)}$	T _{case} = 25°C	•				300		600	
					luty cycle <1%			190		360	
_					t _p < 10 ms, duty cycle <1%			58		115	
2				t _p < 100 ms, duty cycle <1%			30		60	ADC	
MAXIMUM	Maximum Continuous Load Current	$I_{L(max)}$	T _{case} = 25°C	Tong = 25°C Standard devices				2.52			
Ž	N 0 5 5 5: : 5	-	1 0000	Devices with option DLC Standard devices & FC, forced air 4 m/s				40.5	60	05	ADC
	Max. Continuous Power Dissipation	$P_{d(max)}$	T _{case} = 25°C			ed air 4 m/s		10.5 1800		25 2600	Watt
JT.	Linear Derating			Devices with option DLC Standard devices & FC, forced air 4 m/s			0.033		0.06	vvali	
77.0	Linear Derating		Above 25°C		Devices with option DLC			21		40	W/K
4BSOLUTE	Operating Temperature Range	To	Standard devices & options CF, GCF, ILC. (Option DLC)						-4070 (60)		°C
4	Storage Temperature Range	Ts	Switches with option ILC may require frost protection!					-4090			°C
•	Max. Permissible Magnetic Field	В	Homogeneous steady-field, surrounding the whole switch				25			mT	
•	Max. Auxilliary Voltage	V _{aux}	Built-in overvolta	Built-in overvoltage limiter (replaceable)			5.5			VDC	
	Permissible Operating Voltage Range	Vo						0 ± 15			kVDC
	Typical Breakdown Voltage	V_{br}	NOTE: V _{br} is a test parameter for quality control purposes only. Not applicable in normal operation!				16.5			kVDC	
-	Typical Off-State Current	I _{off}	0.8xV _O , T _{case} =2570°C, reduced l _{off} on request				< 80				µADC
	Typical Turn-On Resistance	R _{stat}	Each switching path 0.1 x I _{P(max)} , T _{case} =25°C			0.28 0.14			1		
	'		o,		1.0 x I _{P(max)} , T _{case}			0.6		0.3	
					1.0 x I _{P(max)} , T _{case}	P(max), T _{case} =70°C		1.3		0.65	Ohm
	Typical Propagation Delay Time	Resistive load, 0.1 x I _{P(max)} , 0.8 x V _{O(max)} , 50-50%					200			ns	
	Typical Output Pulse Jitter	t _j		ance matched input, V _{aux} / V _{ctrl} = 5.00 VDC					3		ns
	Typical Turn-On Rise Time	$t_{r(on)}$	Resistive load, 10-90% 0.1 x V _{O(max),} I _L					22		23	
		t _{off} , t _q			0.8 x V _{O(max)} , I _L			38		43	
					$0.8 \times V_{O(max)}$, $I_L = 1.0 \times I_{p(max)}$			45		52	
Ś	Typical Turn-Off Rise Time		Resistive load,	10-90%	$0.1 \times V_{O(max)}, I_L = 0.1 \times I_{p(max)}$		50 100				
TERISTICS		$0.8 \text{ x V}_{O(max)}, I_L = 1.0 \text{ x } I_{p(max)}$				**			ns		
818	Maximum Turn-On Time	ton(max)	No limitation						∞ 400		ns
TEI	Minimum Turn-On Time	t _{on(min)}	t _{on(min)} can be customized. Please consult factory						120		ns
S	Maximum Turn-Off Time Minimum Turn-Off Time	toff(max)	No limitation						∞ 120		ns
-	Max. Continuous Switching	t _{off(min)}						11	120	15	ns
	Frequency	I(max)	Sw. shutdown if	devices with HFS		40			40		
		f _(max) is exceeded Opt. HFS + sufficient cooling option					80		80	kHz	
ELECTRICAL	Maximum Burst Frequency				se option HFB for >10 pulses within 20µs or less				500		kHz
TR	Maximum Number of Pulses / Burst N _(max)		@ f _{b(max)} Standard						>10		1
EC			Note: Option HFB requires external buffer capacitors with a voltage rating of > Option I-HFB				>100				
		630VDC and a capacitance of 100nF per additional pulse. Option HFB						>1000		Pulses	
	Coupling Capacitance	HV side against control side				<100			pF		
	Natural Capacitance C _N		Between switch poles, @ 0.5 x V _{O(max)}				<50 3 10			pF	
	Control Voltage Range V _{ctrl} Auxiliary Supply Voltage Range V _{aux}		The V _{ctrl} has no impact on the output pulse shape. The +5 V supply is not required in the HFS mode.			3 10 4.5 5.5			VDC VDC		
	, 11,		V _{aux} = 5.00 VDC			0.01 x f _(max)	4.5 5.5			VDC	
	Typical Auxiliary Supply Current laux					@ f _(max)		800		800	mADC
-	Fault Signal Output			Active current limitation above 1A. @ f _(max) Switch will be turn off, if f>f _(max) , V _{aux} <4.75V or T _{case} >75°C			>4.0			11.2.12.0	
	r dan Olynar Odipat		Fault condition is indicated by a logical "L"						<0.8		VDC
•	Opt. HFS, Ext. Supply Voltage V1 VHFS(V1		Stability ±3%, current consumption <0.4 mA/kHz @ 25°C						15		VDC
	Opt. HFS, Ext. Supply Voltage V2	Stability ±3%, current consumption <0.5 mA/kHz @ 25°C					62		TBD	VDC	
	Intrinsic Diode Forward Voltage	$T_{case} = 25^{\circ}C, I_F = 0.3 \text{ x } I_{P(max)}$						25		VDC	
	Diode Reverse Recovery Time	$T_{case} = 25^{\circ}C, I_F = 0.3 \text{ x } I_{P(max)}, di/dt = 100 \text{ A/µs}$						<50ns		ns	
6	Dimensions	Standard housing					TBD				
HOUSING			Devices with option DLC					mr			
S	Weight		Standard housing						TBD		
HC		Devices with option DLC					g				
								1			
	Control Signal Input Pin 1 / Yellow (LS-C: Pin 1). TTL compatible (LS-C: With 100Ω termination). Schmitt-Trigger characteristics. Control voltage 2-10 V (3-5 V for low jitter).										ter).
NS	Logic GND / 5V Return Pin 2 / Black (LS-C: Shielding). The ground pin is internally connected with the safety earthings terminals (threaded inserts) on bottom side.										
10	5V Auxiliary Supply Pin 3 / Red (LS-C: Pin 4). The 5 V input is used for rep rates up to the specified max. frequency f _(max) . Higher rep rates require option HFS.										
-	Fault Signal Output Pin 4 / Orange (LS-C: Pin 3). TTL output, short circuit proof. Indicating switch &									-	
	Inhibit Signal Input Pin 5 / Green (LS-C: Pin 2). TTL compatible, Schmitt-Trigger characteristics for the project of the proj										
7	LED Indicators GREEN. Auxiliary power good, switch OFF. TELLOW. Control signal received, switch ON. RED. Fault Condition, switch OFF										
	Tama anakan Basasan Ingga										ifooti
			A Ontion ID	· · · · ·			anacitors)	Option I-PC Option UL-94	Integrated part components acc Flame retardant casting resin, I		mcation.
	<u> </u>	ch, 15kV, 300		High Frequency	Burst (improved canal)	ollity by external ca	ιρασιτοίοι		Fidille letatuatii casiinti tesii i	UL34-VU	
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS	High Frequency	Switching (two auxiliar		. , _	Option I-FWD	Integrated Free-Wheeling Diode. I	In connection with inductive I	
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS Option I-HFS	High Frequency Integrated High	y Switching (two auxiliar Frequency Burst	y supply inputs V1	. , _	Option I-FWD Option I-FWDN	Integrated Free-Wheeling Diode. I Integrated Freewheeling Diode Ne	In connection with inductive letwork. In connection with inc	nductive load.
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS Option I-HFS Option S-TT	High Frequency Integrated High Soft Transition Ti	y Switching (two auxiliar Frequency Burst ime decrease the rise and	y supply inputs V1	1 & V2)	Option I-FWD Option I-FWDN Option PT-C	Integrated Free-Wheeling Diode. I Integrated Freewheeling Diode Ne Pigtail for control connection: Flexi	In connection with inductive letwork. In connection with indible leads (I=75mm) with lem	nductive load. mo
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS Option I-HFS	High Frequency Integrated High Soft Transition Ti Individually incr	y Switching (two auxiliar Frequency Burst	y supply inputs V1 fall time by 20% o avoid unwanted	triggering	Option I-FWD Option I-FWDN	Integrated Free-Wheeling Diode. I Integrated Freewheeling Diode Ne	In connection with inductive letwork. In connection with indible leads (I=75mm) with lem	nductive load. mo
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS Option I-HFS Option S-TT Option Min-On Option Min-Off Option PCC	High Frequency Integrated High Soft Transition Ti Individually incr Individually incr Pulser Configur	y Switching (two auxiliar r Frequency Burst ime decrease the rise and reased "Min. On-Time" to reased "Min. Off-Time" to ration. Switch combined	y supply inputs V1 fall time by 20% o avoid unwanted o avoid unwanted with custom speci	triggering triggering	Option I-FWD Option I-FWDN Option PT-C Option SEP-C Option TH Option CF	Integrated Free-Wheeling Diode. I Integrated Freewheeling Diode Ne Pigtall for control connection: Flexi Separated control unit. Control uni Tubular Housing Copper Cooling Fins. P _{d(max)} ca	In connection with inductive letwork. In connection with in ible leads (I=75mm) with lem it with LED indicators in a send to be increased by the fact	nductive load. mo eparate
	HTS 151-30 SiC Fast HV SiC Mosfet Switch	ch, 15kV, 300	A Option HFB Option HFS Option I-HFS Option S-TT Option Min-On Option Min-Off	High Frequency Integrated High Soft Transition Ti Individually incr Individually incr Pulser Configur 40kV Isolation.	y Switching (two auxiliar Frequency Burst ime decrease the rise and reased "Min. On-Time" to reased "Min. Off-Time" to	y supply inputs V1 fall time by 20% o avoid unwanted o avoid unwanted with custom speci sed to 120kV.	triggering triggering	Option I-FWD Option I-FWDN Option PT-C Option SEP-C Option TH Option CF Option DLC	Integrated Free-Wheeling Diode. I Integrated Freewheeling Diode Ne Pigtail for control connection: Flexi Separated control unit. Control unit Tubular Housing	In connection with inductive letwork. In connection with in ible leads (I=75mm) with lem it with LED indicators in a se in be increased by the factor 10 be	nductive load. mo eparate ctor 3 to 10. 0 to 100.